In place of PTO-1449 Form	U. S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE			*Complete if Known*	
				Application Number	Continuation of 10/120,872
INFORMATION DISCLOSURE STATEMENT BY APPLICANT *(use as many sheets as necessary)*				Filing Date	Herewith
				Applicant(s)	Kitsukawa, et al.
				Art Unit	Unknown
				Examiner Name	Unknown
SHEET	1	OF	1	Attorney Docket Number	5774.60

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Examiner's Initials	Cite No.	Document Number	Publication Date (MM/YYYY)	Name of Patentee or Applicant of Cited Document
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DM	AI	EP 0239913 A2	07/1987	Fujitsu Ltd.	English
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OTHER PRIOR ART

Examiner's Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article, title of the item, date, page(s), volume-issue number(s), publisher, city/country where published.
DM	AK	NODA et al., A Boosted Dual Word-Line Decoding Scheme for 256 Mb DRAMs, pp. 112-113.
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Examiner Signature		Date Considered	4/11/04

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include a copy of this form with next communication to applicant.